

1-Line, Bi-directional, Ultra-low Capacitance

Description

PESDR1821P1A is an ultra-low capacitance TVS (Transient Voltage Suppressor) designed to protect high speed data interfaces. It has been specifically designed to protect sensitive electronic components which are connected to data and transmission lines from over-stress caused by ESD (Electrostatic Discharge). PESDR1821P1A may be used to provide ESD protection up to ±15KV (air and contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 4A (8/20µs) according to IEC61000-4-5.

Features

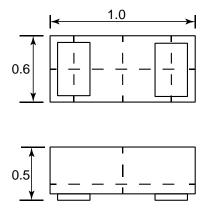
- Ultra small package: 1.0x0.6x0.5mm
- Protects one data or power line
- Low operating voltage: 18V
- 2-pin leadless package
- Complies with following standards:
 - —IEC 61000-4-2 (ESD) immunity test

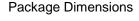
Air discharge: ±15kV
Contact discharge: ±15kV

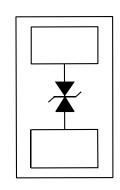
—IEC61000-4-5 (Lightning)5A (8/20μs)

RoHS Compliant

Dimensions and Pin Configuration







Circuit and Pin Schematic

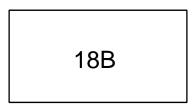
Mechanical Characteristics

- Package: DFN1006-2 (1.0×0.6×0.5mm)
- · Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- USB 2.0 and USB 3.0
- HDMI 1.3. HDMI 1.4 and HDMI 2.0
- SATA and e SATA interface
- DVI
- IEEE 1394
- Portable Electronics and Notebooks

Marking Information



18B = Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PESDR1821P1A	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (TA=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20μs)	P _{PK}	35	W	
Peak Pulse Current (8/20µs)	Ірр	5	А	
ESD per IEC 61000-4-2 (Air)	V	±15	- kV	
ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±15		
Lead temperature	TL	260	°C	
Operating Temperature Range	Тор	-40 ~ + 85	°C	
Storage Temperature Range	Тѕтс	−55 ~ + 150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

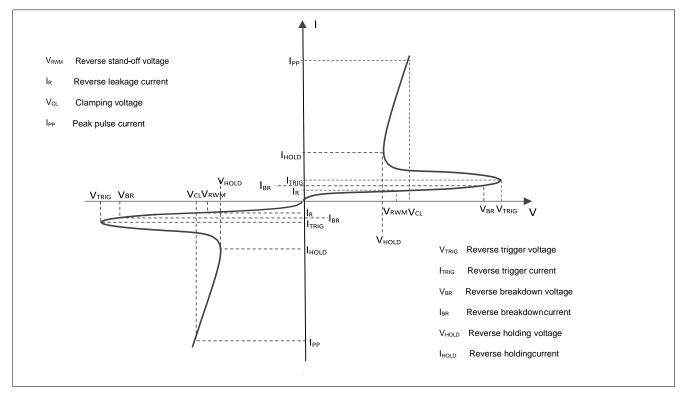
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			18	٧	
Breakdown Voltage	V_{BR}	19	21	23	V	$I_T = 1mA$
Reverse Leakage Current	I _R			0.1	μA	V _{RWM} = 18V
Clamping voltage 1)	V _{CL}		9.0		V	$I_{PP} = 16A, t_p = 100ns$
Dynamic resistance 1)	R _{DYN}		0.33		Ω	
Clamping voltage 2)	V _{CL}		9.0		V	V _{ESD} = 8kV
Clamping Voltage ³⁾	Vc			5	V	I _{PP} = 1A (8/20µs pulse)
Clamping Voltage ³⁾	Vc			7	V	I _{PP} = 5A (8/20µs pulse)
Junction Capacitance	Сл		0.50	0.70	pF	V _R = 0V, f = 1MHz

Notes:

- 1) TLP parameter: $Z_0 = 50\Omega$, $t_0 = 100$ ns, t_0
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.



Electrical characteristics (T_A = 25°C, unless otherwise noted)



Definitions of electrical characteristics

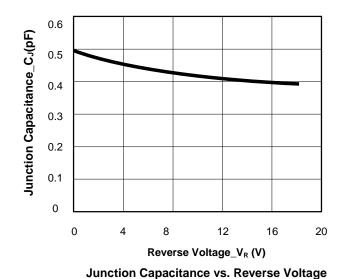


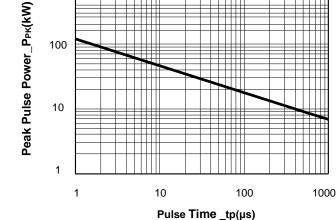
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

1000

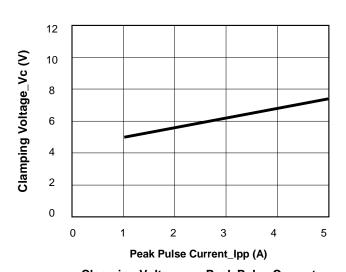
100

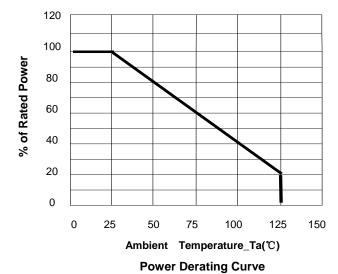
10

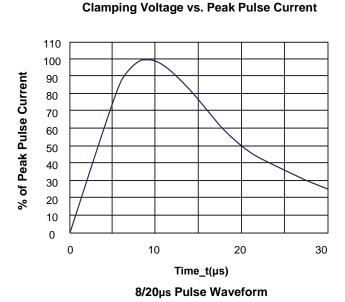


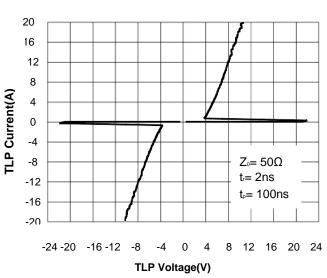


Peak Pulse Power vs. Pulse Time





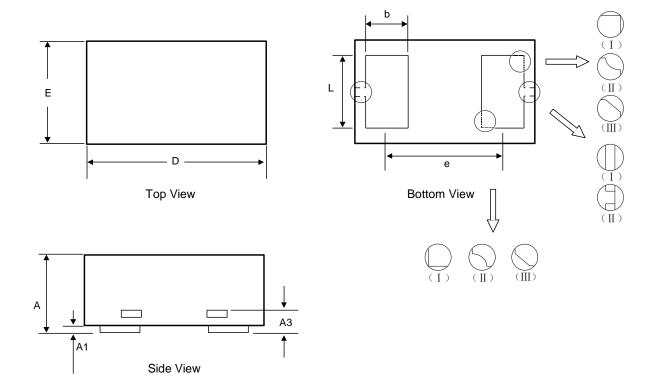




TLP Measurement

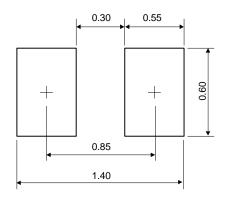


DFN1006-2 Package Outline Drawing



Symbol	Dimensions in Millimeters			
	Min.	Тур.	Max.	
A	0.340	0.450	0.550	
A1	0.000	0.020	0.050	
A3	0.125 Ref.			
D	0.950	1.000	1.075	
E	0.490	0.600	0.675	
b	0.200	0.250	0.300	
L	0.450	0.500	0.550	
e	0.650 BSC			

Recommended PCB Layout (Unit: mm)



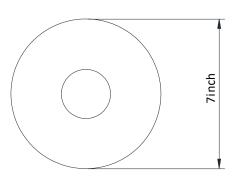
Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

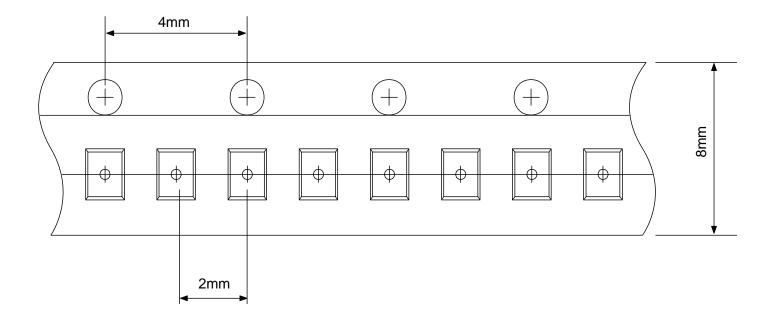


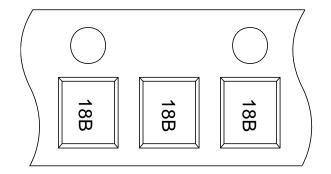
TAPE AND REEL INFORMATION





Tape Dimensions







User Direction of Feed



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